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April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<http://www.renesas.com>)

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H5N2517FN

Silicon N Channel MOS FET
High Speed Power Switching

REJ03G0371-0100Z

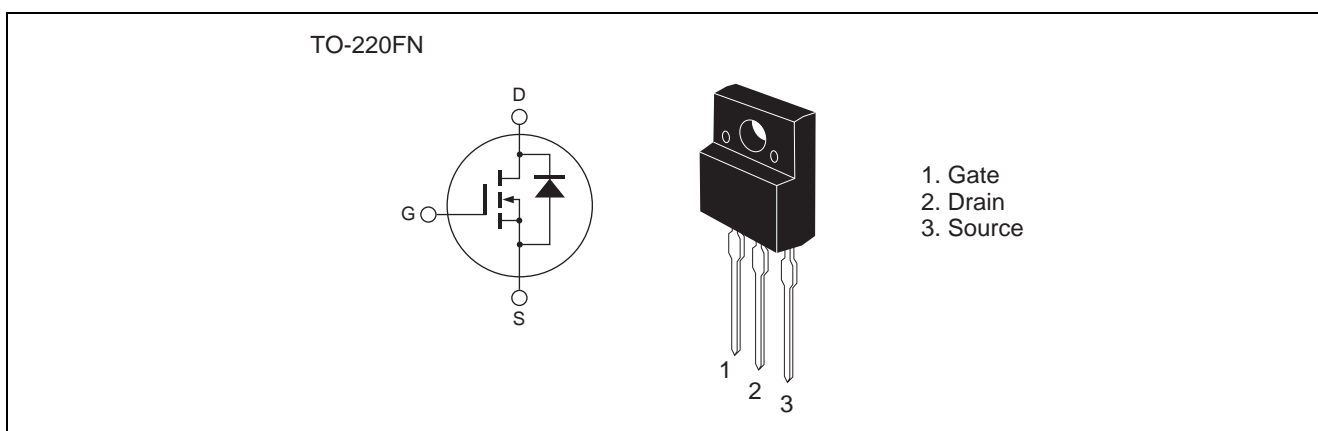
Rev.1.00

May.28.2004

Features

- Low on-resistance
- Low leakage current
- High speed switching

Outline



Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Ratings	Unit
Drain to Source voltage	V_{DSS}	250	V
Gate to Source voltage	V_{GSS}	±30	V
Drain current	I_D	20	A
Drain peak current	$I_{D(pulse)}$ ^{Note1}	80	A
Body-Drain diode reverse Drain current	I_{DR}	20	A
Body-Drain diode reverse Drain peak current	$I_{DR(pulse)}$ ^{Note1}	80	A
Avalanche current	I_{AP} ^{Note3}	7	A
Avalanche energy	E_{AR} ^{Note3}	3.0	mJ
Channel dissipation	P_{ch} ^{Note2}	30	W
Channel to case thermal impedance	θ_{ch-c}	4.17	°C/W
Channel temperature	T_{ch}	150	°C
Storage temperature	T_{stg}	-55 to +150	°C

Notes: 1. $PW \leq 10 \mu s$, duty cycle $\leq 1\%$

2. Value at $T_c = 25^\circ C$

3. $STch = 25^\circ C$, $T_{ch} \leq 150^\circ C$

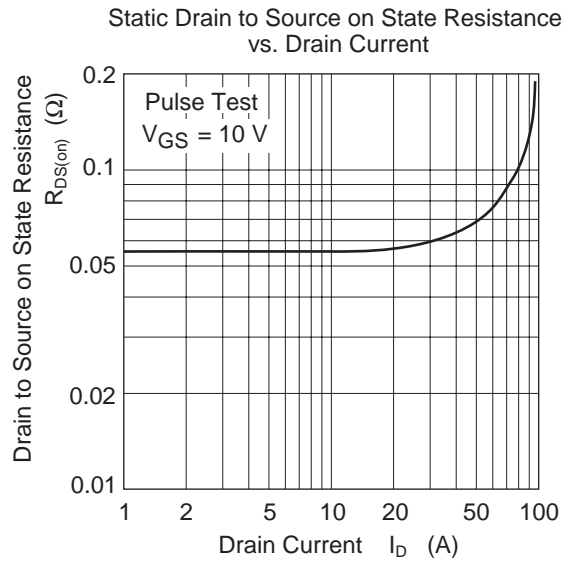
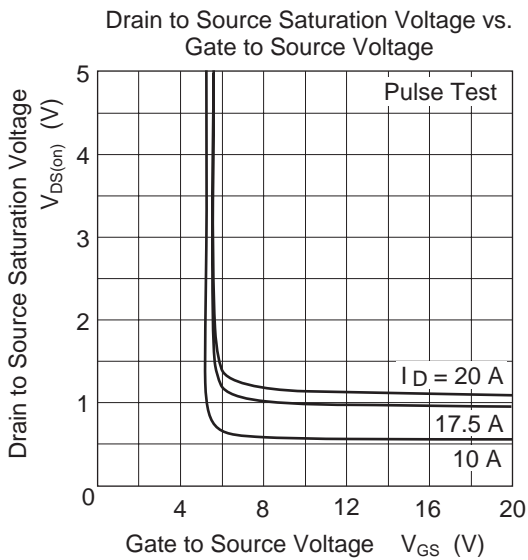
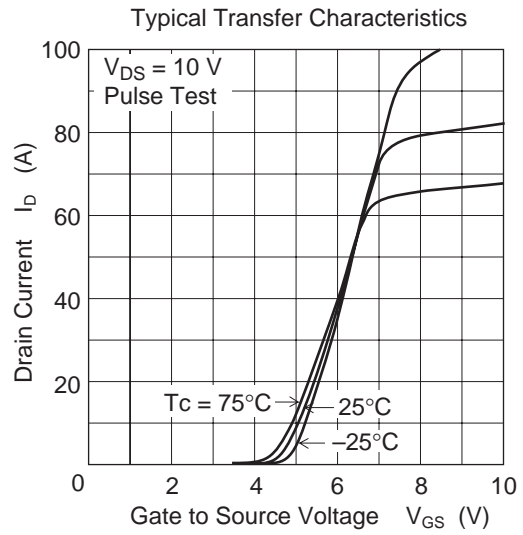
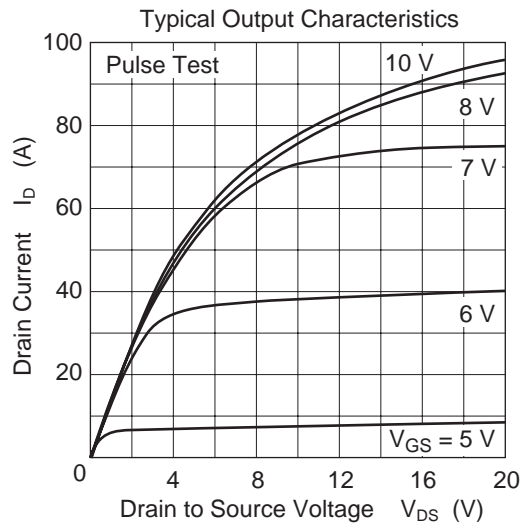
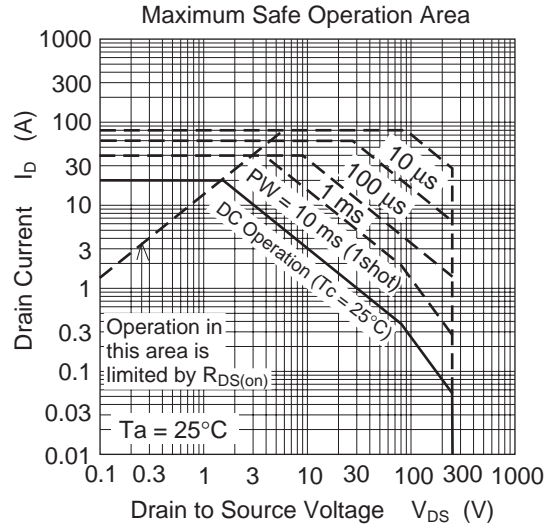
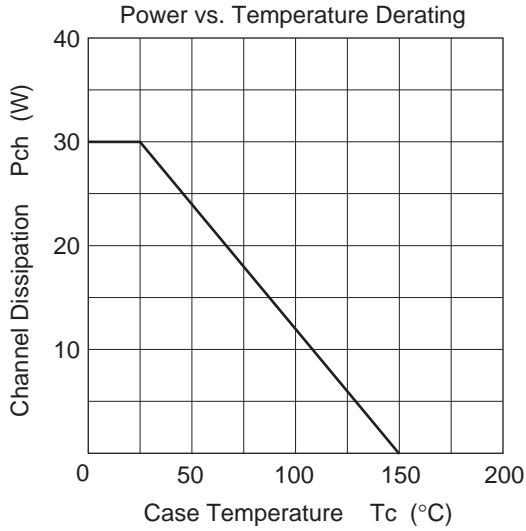
Electrical Characteristics

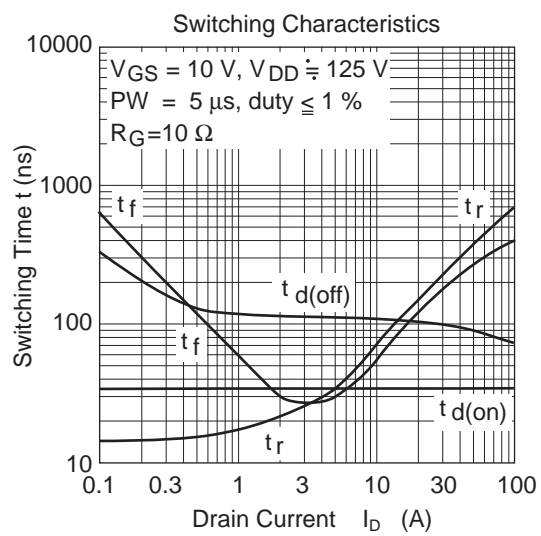
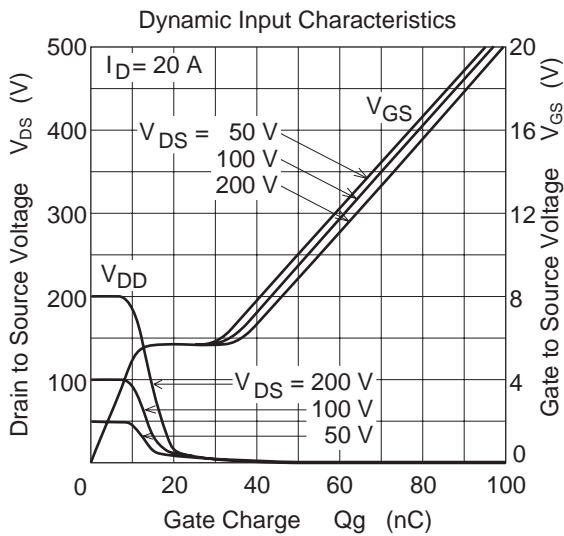
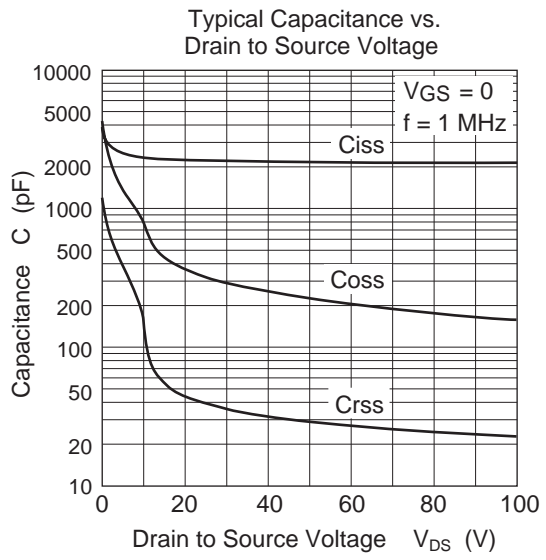
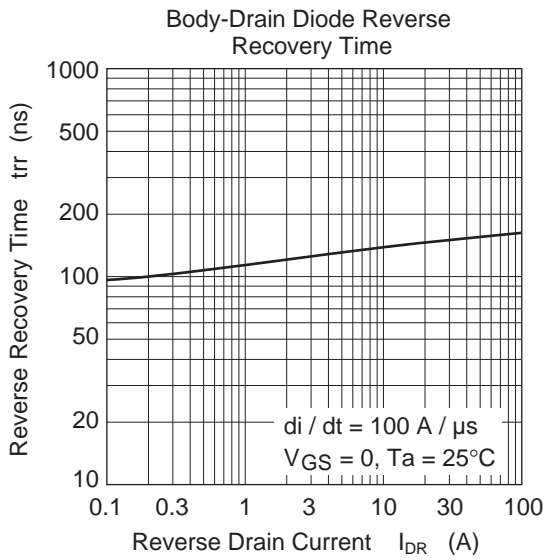
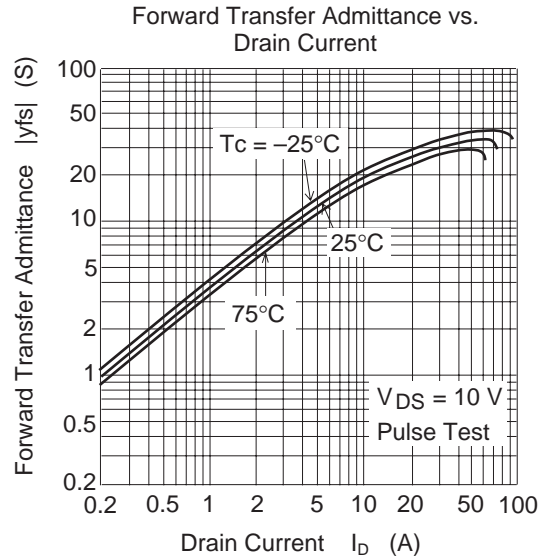
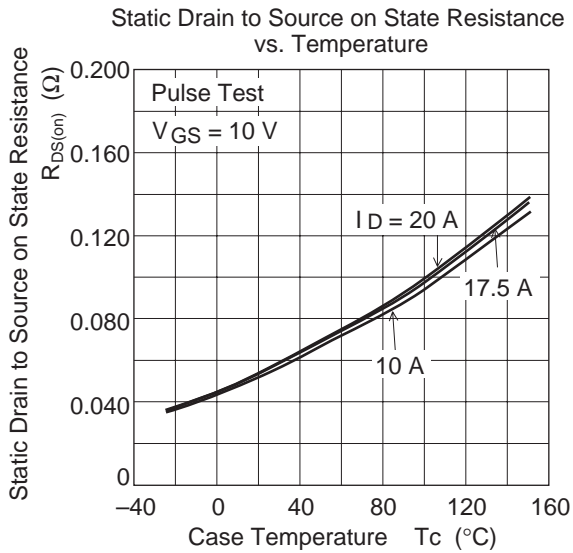
(Ta = 25°C)

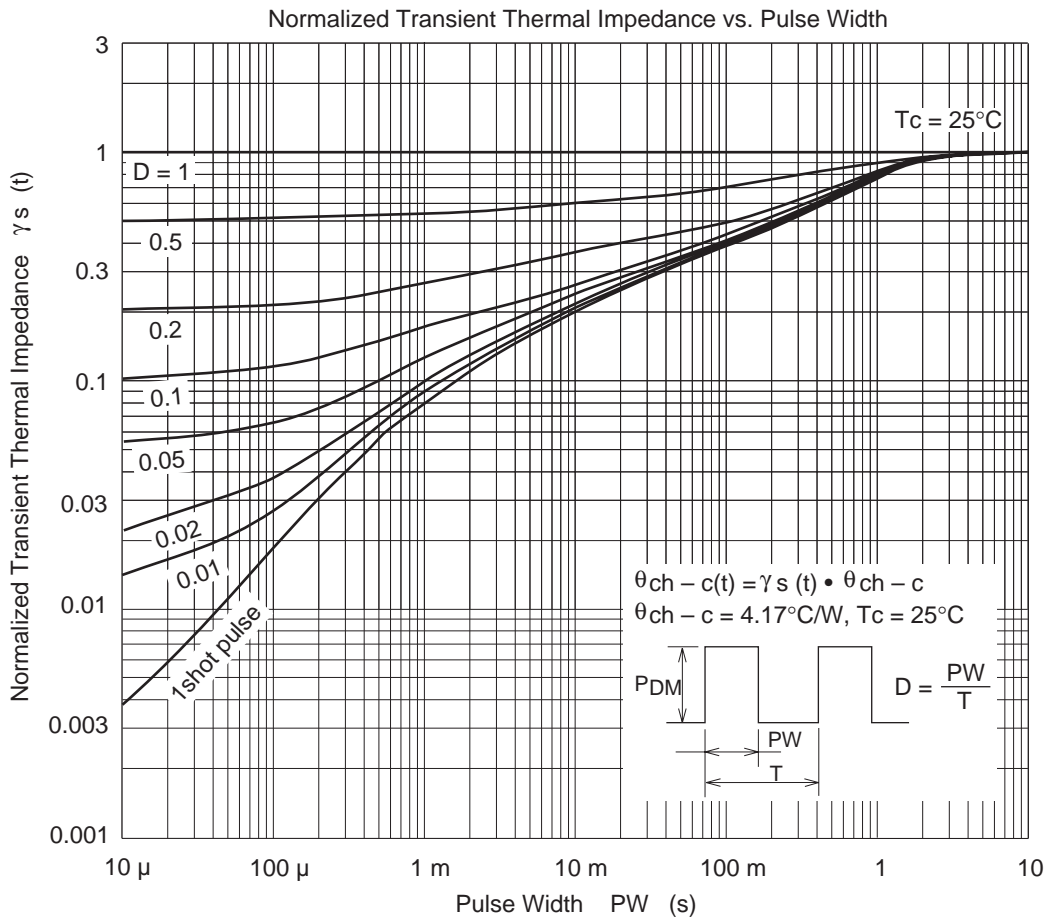
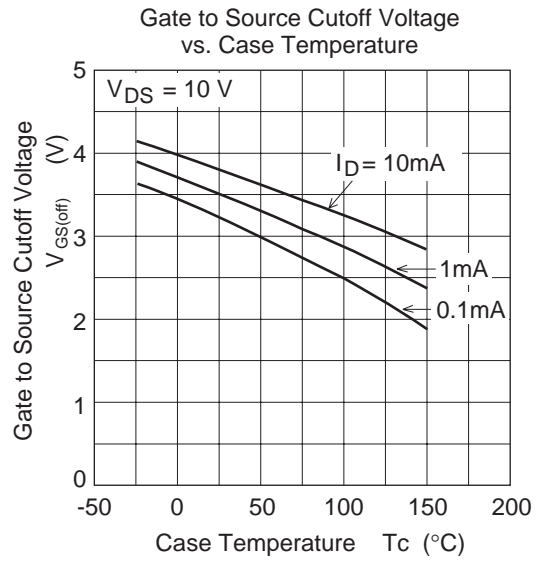
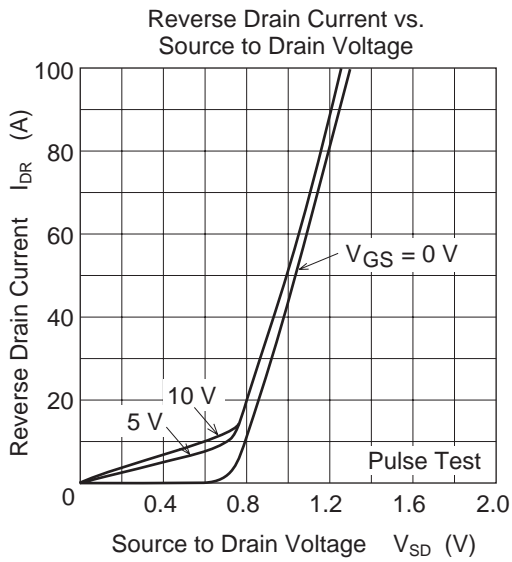
Item	Symbol	Min	Typ	Max	Unit	Test conditions
Drain to Source breakdown voltage	$V_{(BR)DSS}$	250	—	—	V	$I_D = 10 \text{ mA}$, $V_{GS} = 0$
Zero Gate voltage drain current	I_{DSS}	—	—	1	μA	$V_{DS} = 250 \text{ V}$, $V_{GS} = 0$
Gate to Source leak current	I_{GSS}	—	—	± 0.1	μA	$V_{GS} = \pm 30 \text{ V}$, $V_{DS} = 0$
Gate to Source cutoff voltage	$V_{GS(off)}$	3.0	—	4.0	V	$V_{DS} = 10 \text{ V}$, $I_D = 1 \text{ mA}$
Forward transfer admittance	$ y_{fs} $	11	19	—	S	$I_D = 10 \text{ A}$, $V_{DS} = 10 \text{ V}$ ^{Note4}
Static Drain to Source on state resistance	$R_{DS(on)}$	—	0.055	0.072	Ω	$I_D = 10 \text{ A}$, $V_{GS} = 10 \text{ V}$ ^{Note4}
Input capacitance	C_{iss}	—	2200	—	pF	$V_{DS} = 25 \text{ V}$
Output capacitance	C_{oss}	—	320	—	pF	$V_{GS} = 0$
Reverse transfer capacitance	C_{rss}	—	40	—	pF	$f = 1 \text{ MHz}$
Turn-on delay time	$t_{d(on)}$	—	35	—	ns	$I_D = 10 \text{ A}$
Rise time	t_r	—	70	—	ns	$V_{GS} = 10 \text{ V}$
Turn-off delay time	$t_{d(off)}$	—	110	—	ns	$R_L = 12.5 \Omega$
Fall time	t_f	—	55	—	ns	$R_g = 10 \Omega$
Total Gate charge	Q_g	—	56	—	nC	$V_{DD} = 200 \text{ V}$
Gate to Source charge	Q_{gs}	—	13	—	nC	$V_{GS} = 10 \text{ V}$
Gate to Drain charge	Q_{gd}	—	26	—	nC	$I_D = 20 \text{ A}$
Body-Drain diode forward voltage	V_{DF}	—	0.9	1.5	V	$I_F = 20 \text{ A}$, $V_{GS} = 0$ ^{Note4}
Body-Drain diode reverse recovery time	t_{rr}	—	160	—	ns	$I_F = 20 \text{ A}$, $V_{GS} = 0$
Body-Drain diode reverse recovery charge	Q_{rr}	—	0.9	—	μC	$diF/dt = 100 \text{ A}/\mu\text{s}$

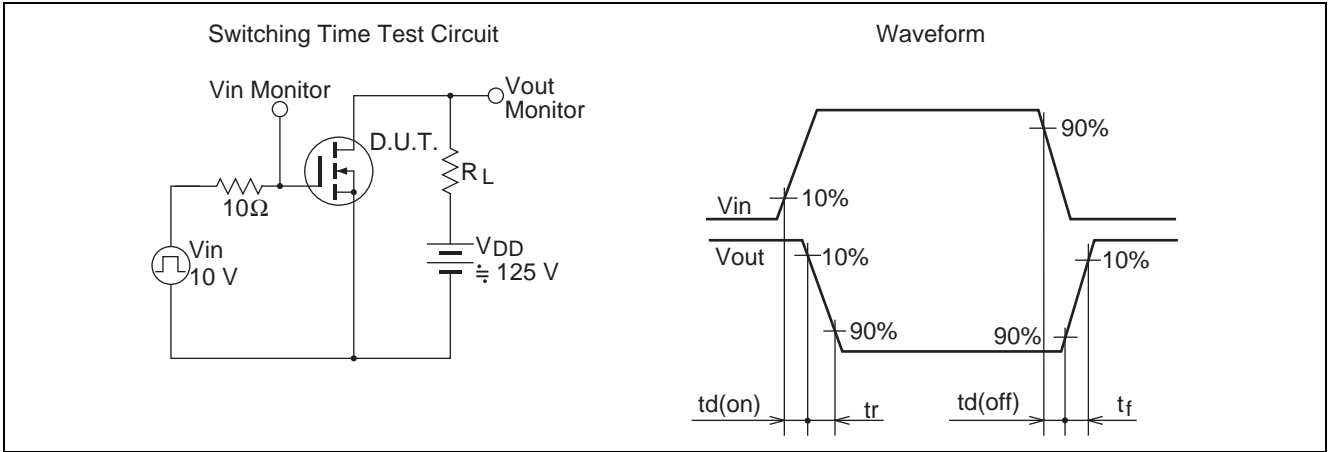
Notes: 4. Pulse test

Main Characteristics

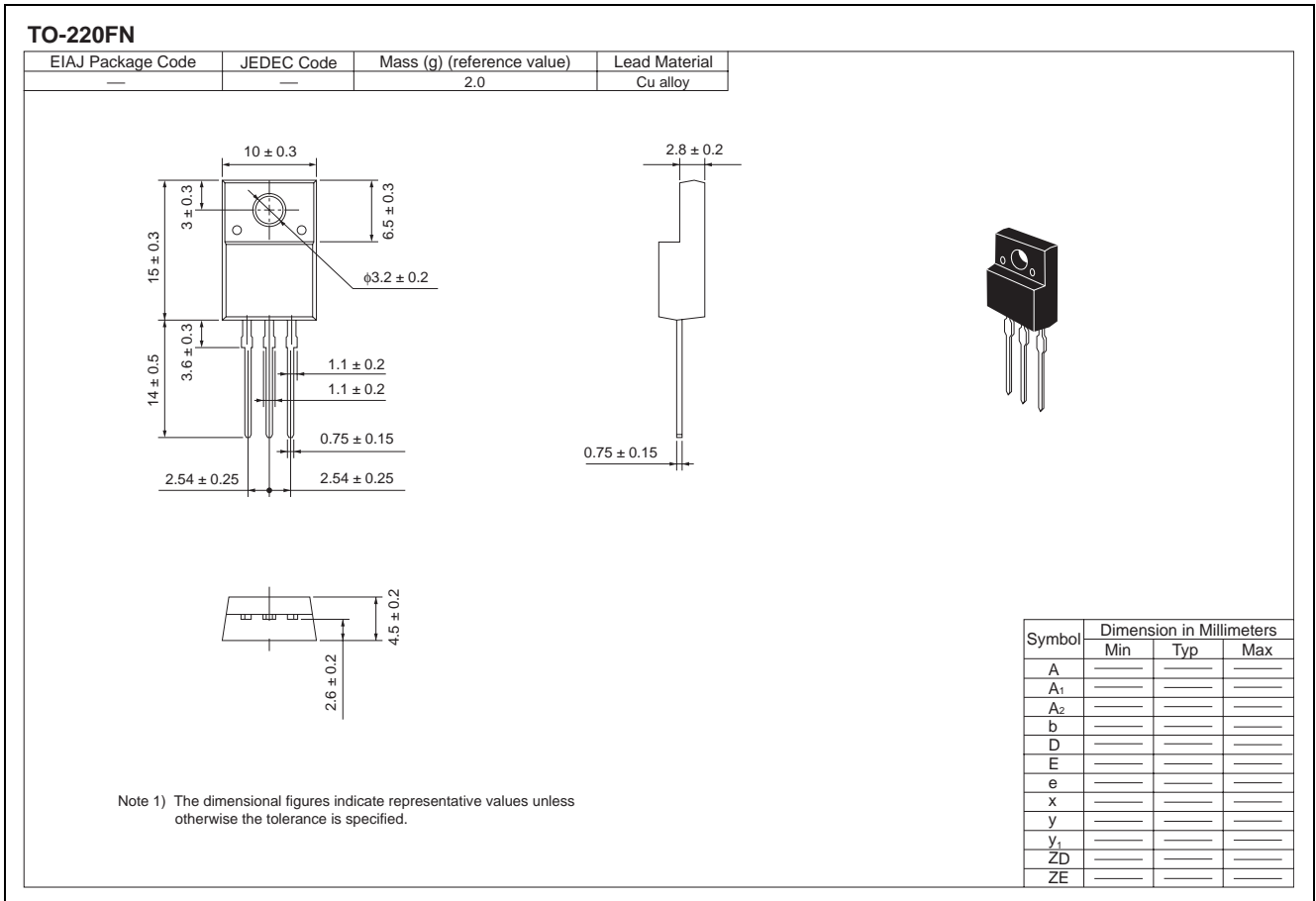








Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
H5N2517FN-E	50 pcs	Plastic magazine

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